

FEATURES

- Circular Active Area
- Ideal for Electron Detection
- 100% Internal QE
- TO-8 Package

Electro-Optical Characteristics at 25°C

Parameters	Test Conditions	Min	Тур	Max	Units
Active Area ¹	Ф 4.9 mm		19		mm ²
Responsivity	(see graph next page)				A/W
Reverse Breakdown Voltage, V _R	$I_R = 1 \mu A$		20		Volts
Capacitance, C	V _R = 0 V		1.2	1.5	nF
Rise Time	$RL = 50 \Omega$, $V_R = 0 V$			1	us
Shunt Resistance	$V_f = \pm 10 \text{ mV}$	50	100		MOhms
Dark Current	V _R = 13 V			30	nA

¹ Die active area = Φ 5.5 mm, aperture size = Φ 4.9 mm.

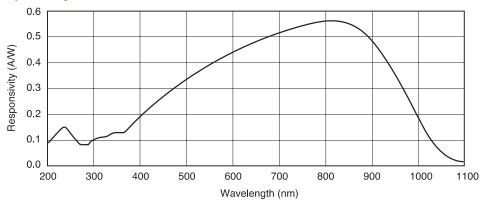
Thermal Parameters

Storage and Operating Temperature Range	Units		
Storage Temperature Range	-20°C to 100°C		
Operating Temperature Range	20°C to 80°C		
Lead Soldering Temperature ¹	240°C		

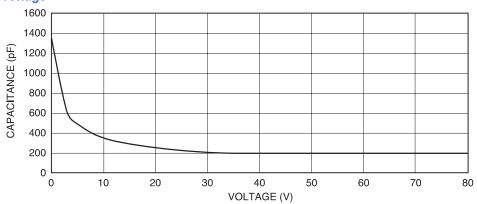
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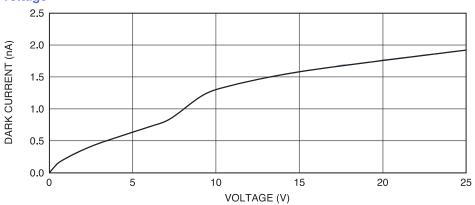
Typical Photon Responsivity



Capacitance vs. Voltage



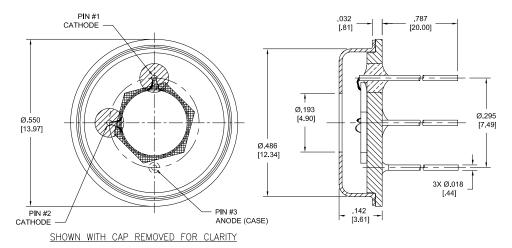
Dark Current vs. Voltage



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Package Information



Dimensions are in inch [metric] units.

Specifications are subject to change without prior notice.

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